RENESAS

HVD191

Silicon Epitaxial Planar PIN Diode for High Frequency Attenuator

REJ03G0015-0100Z Rev.1.00 Apr.28.2003

Features

- Low capacitance. ($C \le 0.37 \text{ pF}$)
- Low forward resistance. (rf $\leq 2.5 \Omega$)
- Super small Flat Package (SFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVD191	H2	SFP

Pin Arrangement

1 🗆	Cathode mark Mark H2 2	1. Cathode
		2. Anode

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V _R	30	V
Forward current	I _F	100	mA
Power dissipation	Pd	150	mW
Junction temperature	Tj	125	°C
Storage temperature	Tstg	–55 to +125	°C

Electrical Characteristics

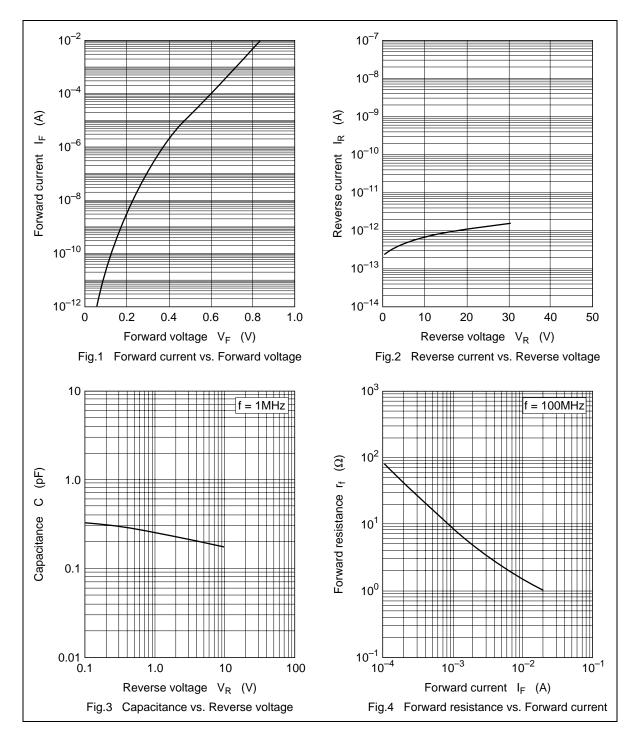
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V _F			1.0	V	I _F = 10 mA
Reverse current	I _R	_	_	0.1	μΑ	V _R = 30 V
Capacitance	С			0.37	pF	$V_{R} = 1 V, f = 1 MHz$
Forward resistance	r _f	_		2.5	Ω	I _F = 10 mA, f = 100 MHz

Notes: 1. Please do not use the soldering iron due to avoid high stress to the SFP package.

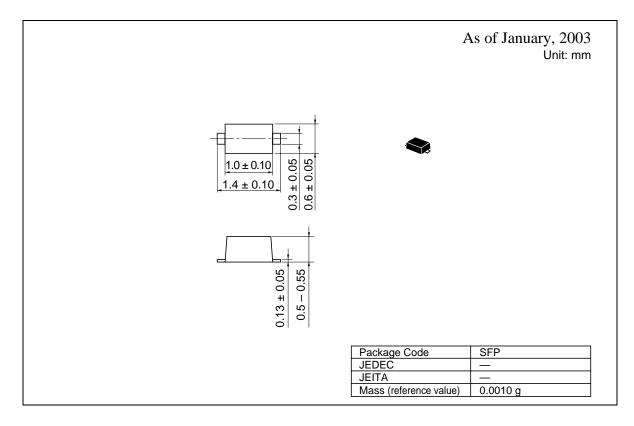
2. The material of lead is exposed for cutting plane. Therefore, soldering nature of lead tip part is considered as unquestioned. Please kindly consider soldering nature.

Main Characteristic



HVD191

Package Dimensions



Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Keep safety first in your circuit designs!

The particle is a straight of the indexesting is a straight of the particle is a straight of

Notes regarding these materials

- Notes regarding these materials
 1. These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corporation product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corporation or a third party.
 2. Renesas Technology Corporation assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials.
 3. All information contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Renesas Technology Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact Renesas Technology Corporation or an authorized Renesas Technology Corporation product best product information before purchasing a product listed herein.
 The information described here may contain technical inaccuracies or typographical errors.
 Renesas Technology Corporation assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors.
 Please also pay attention to information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making all decision on the applicability of the information and products. Renesas Technology Corporation serves no teoponsibility for any damage, liability, or other loss resulting from the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision

- Refease retring the control semiconductors are not designed or manufactured to use in a device or system har is used under circumstances in which number harman is potential at stake. Please contact Renesas Technology Corporation or an authorized Renesas Technology Corporation or an authorized Renesas Technology Corporation or an authorized Renesas Technology Corporation or product distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
 The prior written approval of Renesas Technology Corporation is necessary to reprint or reproduce in whole or in part these materials.
 If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination.

- Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited. 8. Please contact Renesas Technology Corporation for further details on these materials or the products contained therein.



http://www.renesas.com

Copyright © 2003. Renesas Technology Corporation, All rights reserved. Printed in Japan. Colophon 0.0

